

Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Original) A piezoelectric single crystal having a complex perovskite structure, wherein the composition of the piezoelectric single crystal contains 35 to 98 mol% lead magnesium niobate $[\text{Pb}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3]$ or lead zinc niobate $[\text{Pb}(\text{Zn}_{1/3}\text{Nb}_{2/3})\text{O}_3]$, 0.1 to 64.9 mol% lead titanate $[\text{PbTiO}_3]$, and 0.05 to 30 mol% lead indium niobate $[\text{Pb}(\text{In}_{1/2}\text{Nb}_{1/2})\text{O}_3]$; and calcium is substituted for 0.05 to 10 mol% lead in the composition.

2. (Canceled)

3. (Previously Presented) A piezoelectric single-crystal device having the polarization direction in a $[001]$ direction of an ingot of the piezoelectric single crystal according to claim 1 and using an electromechanical coupling factor (k_{31}) in a lateral vibration mode having the end face in a plane perpendicularly cutting a (001) plane containing a $[100]$ direction and a $[010]$ direction being approximately orthogonal to the polarization direction, wherein

when the $[100]$ direction or the $[010]$ direction is defined as 0° , a direction normal to the end face resides within $0^\circ \pm 15^\circ$ or within $45^\circ \pm 5^\circ$.

4. (Previously Presented) A piezoelectric single-crystal device having the polarization direction in a $[001]$ direction of an ingot of the piezoelectric single crystal according to claim 1 and using an electromechanical coupling factor (k_{31}) in a lateral vibration mode having a direction normal to the end face of the single-crystal device in a $[100]$ direction, a $[010]$ direction, or a $[110]$ direction being approximately orthogonal to the polarization direction, wherein

the direction normal to the end face of the single crystal resides in a solid angle of the [100] axis $\pm 15^\circ$, in a solid angle of the [010] axis $\pm 15^\circ$, or in a solid angle of the [110] axis $\pm 5^\circ$.

5. (Previously Presented) A piezoelectric single-crystal device having the polarization direction in a [001] direction of an ingot of the piezoelectric single crystal according to claim 1 and using an electromechanical coupling factor (k_{33}) in a vibration mode in the direction parallel to the polarization direction, i.e., in a longitudinal vibration mode having the end face in a (001) plane, wherein

when the shortest-side length or the diameter of the device end face orthogonal to the polarization direction is defined as a and the device length in the direction parallel to the polarization direction is defined as b , the piezoelectric single-crystal device has the a and the b satisfying the relational formula $b/a \geq 2.5$.

6. (Previously Presented) A piezoelectric single-crystal device having the polarization direction in a [110] direction of an ingot of the piezoelectric single crystal according to claim 1 and using an electromechanical coupling factor (k_{33}) in a vibration mode in the direction parallel to the polarization direction, i.e., in a longitudinal vibration mode having the end face in a (110) plane, wherein

when the shortest-side length or the diameter of the device end face orthogonal to the polarization direction is defined as a and the device length in the direction parallel to the polarization direction is defined as b , the piezoelectric single-crystal device has the a and the b satisfying the relational formula $b/a \geq 2.5$.

7. (Previously Presented) A 1-3 piezoelectric composite formed by arraying a plurality of the piezoelectric single-crystal devices according to claim 5 in such a manner that the device end faces orthogonal to the polarization direction reside in one plane.

8. (Previously Presented) A method for manufacturing the piezoelectric single-crystal device according to claim 3, the method comprising a polarizing process carried out before or after the cutting of an ingot of a piezoelectric single crystal having a complex perovskite structure wherein the composition of the piezoelectric single crystal contains 35 to 98 mol% lead magnesium niobate $[\text{Pb}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3]$ or lead zinc niobate $[\text{Pb}(\text{Zn}_{1/3}\text{Nb}_{2/3})\text{O}_3]$, 0.1 to 64.9 mol% lead titanate $[\text{PbTiO}_3]$, and 0.05 to 30 mol% lead indium niobate $[\text{Pb}(\text{In}_{1/2}\text{Nb}_{1/2})\text{O}_3]$; and calcium is substituted for 0.05 to 10 mol% lead in the composition, into a single-crystal device material having a predetermined shape in a predetermined direction, wherein the single-crystal ingot or the single-crystal device material is polarized by applying a direct electric field of 350 to 1500 V/mm in the temperature range of 20 to 200°C in a direction to be polarized of the single-crystal ingot or in a direction to be polarized of the cut-out single-crystal device material; or applying a direct electric field of 350 to 1500 V/mm at a temperature higher than the Curie temperature (T_c) of the single-crystal ingot or the single-crystal device material and then cooling to a room temperature while applying the direct electric field.

9.-15. (Canceled)

16. (Previously Presented) A 1-3 piezoelectric composite formed by arraying a plurality of the piezoelectric single-crystal devices according to claim 6 in such a manner that the device end faces orthogonal to the polarization direction reside in one plane.

17. (Previously Presented) A method for manufacturing the piezoelectric single-crystal device according to claim 3, the method comprising a polarizing process carried out before or after the cutting of an ingot of a piezoelectric single crystal having a complex perovskite structure wherein the composition of the piezoelectric single crystal contains 35 to 98 mol% lead magnesium niobate $[\text{Pb}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3]$ or lead zinc niobate $[\text{Pb}(\text{Zn}_{1/3}\text{Nb}_{2/3})\text{O}_3]$, 0.1 to 64.9 mol% lead titanate $[\text{PbTiO}_3]$, and 0.05 to 30 mol% lead

indium niobate $[\text{Pb}(\text{In}_{1/2}\text{Nb}_{1/2})\text{O}_3]$; calcium is substituted for 0.05 to 10 mol% lead in the composition; and the composition further contains 5 mol% or less in total of at least one element selected from the group consisting of Mn, Cr, Sb, W, Al, La, Li, and Ta, into a single-crystal device material having a predetermined shape in a predetermined direction, wherein the single-crystal ingot or the single-crystal device material is polarized by applying a direct electric field of 350 to 1500 V/mm in the temperature range of 20 to 200°C in a direction to be polarized of the single-crystal ingot or in a direction to be polarized of the cut-out single-crystal device material; or applying a direct electric field of 350 to 1500 V/mm at a temperature higher than the Curie temperature (T_c) of the single-crystal ingot or the single-crystal device material and then cooling to a room temperature while applying the direct electric field.

18. (Canceled)